## Hehai Fang

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Progress, Challenges, and Opportunities for 2D Material Based Photodetectors. Advanced Functional Materials, 2019, 29, 1803807.	14.9	884
2	Photogating in Low Dimensional Photodetectors. Advanced Science, 2017, 4, 1700323.	11.2	622
3	Plasmonic Silicon Quantum Dots Enabled High-Sensitivity Ultrabroadband Photodetection of Graphene-Based Hybrid Phototransistors. ACS Nano, 2017, 11, 9854-9862.	14.6	285
4	Tunable Ambipolar Polarization-Sensitive Photodetectors Based on High-Anisotropy ReSe <sub>2</sub> Nanosheets. ACS Nano, 2016, 10, 8067-8077.	14.6	276
5	Generalized colloidal synthesis of high-quality, two-dimensional cesium lead halide perovskite nanosheets and their applications in photodetectors. Nanoscale, 2016, 8, 13589-13596.	5.6	252
6	Recent Progress on Localized Field Enhanced Twoâ€dimensional Material Photodetectors from Ultraviolet—Visible to Infrared. Small, 2017, 13, 1700894.	10.0	234
7	Arrayed Van Der Waals Broadband Detectors for Dualâ€Band Detection. Advanced Materials, 2017, 29, 1604439.	21.0	218
8	Highâ€Performance Photovoltaic Detector Based on MoTe <sub>2</sub> /MoS <sub>2</sub> Van der Waals Heterostructure. Small, 2018, 14, 1703293.	10.0	205
9	When Nanowires Meet Ultrahigh Ferroelectric Field–High-Performance Full-Depleted Nanowire Photodetectors. Nano Letters, 2016, 16, 2548-2555.	9.1	135
10	Visible Light-Assisted High-Performance Mid-Infrared Photodetectors Based on Single InAs Nanowire. Nano Letters, 2016, 16, 6416-6424.	9.1	134
11	Highâ€5ensitivity Floatingâ€Gate Phototransistors Based on WS <sub>2</sub> and MoS <sub>2</sub> . Advanced Functional Materials, 2016, 26, 6084-6090.	14.9	124
12	A Broadband Fluorographene Photodetector. Advanced Materials, 2017, 29, 1700463.	21.0	110
13	Highâ€Performance Ferroelectric Polymer Sideâ€Gated CdS Nanowire Ultraviolet Photodetectors. Advanced Functional Materials, 2016, 26, 7690-7696.	14.9	107
14	High-Performance Near-Infrared Photodetectors Based on p-Type SnX (X = S, Se) Nanowires Grown <i>via</i> Chemical Vapor Deposition. ACS Nano, 2018, 12, 7239-7245.	14.6	101
15	Optoelectronic Properties of Printed Photogating Carbon Nanotube Thin Film Transistors and Their Application for Light-Stimulated Neuromorphic Devices. ACS Applied Materials & Interfaces, 2019, 11, 12161-12169.	8.0	80
16	Etching Techniques in 2D Materials. Advanced Materials Technologies, 2019, 4, 1900064.	5.8	50
17	Room-Temperature Single-Photon Detector Based on Single Nanowire. Nano Letters, 2018, 18, 5439-5445.	9.1	42
18	Novel Typeâ€II InAs/AlSb Core–Shell Nanowires and Their Enhanced Negative Photocurrent for Efficient Photodetection. Advanced Functional Materials, 2018, 28, 1705382.	14.9	36

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19	SWCNTâ€MoS <sub>2</sub> â€SWCNT Vertical Point Heterostructures. Advanced Materials, 2017, 29, 1604469.	21.0	32
20	Nonlocal Response in Infrared Detector with Semiconducting Carbon Nanotubes and Graphdiyne. Advanced Science, 2017, 4, 1700472.	11.2	29
21	Significant Enhancement of Single-Walled Carbon Nanotube Based Infrared Photodetector Using PbS Quantum Dots. IEEE Journal of Selected Topics in Quantum Electronics, 2018, 24, 1-8.	2.9	19
22	Global Photocurrent Generation in Phototransistors Based on Singleâ€Walled Carbon Nanotubes toward Highly Sensitive Infrared Detection. Advanced Optical Materials, 2019, 7, 1900597.	7.3	15
23	Ambipolar and Robust WSe 2 Fieldâ€Effect Transistors Utilizing Selfâ€Assembled Edge Oxides. Advanced Materials Interfaces, 2020, 7, 1901628.	3.7	11
24	Hybrid heterojunctions based on 2D materials and 3D thin-films for high-performance photodetectors. Science China: Physics, Mechanics and Astronomy, 2017, 60, 1.	5.1	8
25	Optoelectronics: Highâ€Performance Photovoltaic Detector Based on MoTe <sub>2</sub> /MoS <sub>2</sub> Van der Waals Heterostructure (Small 9/2018). Small, 2018, 14, 1870038.	10.0	7
26	Photodetectors: A Broadband Fluorographene Photodetector (Adv. Mater. 22/2017). Advanced Materials, 2017, 29, .	21.0	1